# NSN 5961-01-049-1535

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-049-1535

# Inclosure Material:

Metal

# Overall Length:

Between 0.170 inches and 0.210 inches

# Terminal Length:

Between 0.500 inches and 0.750 inches

#### **Overall Diameter:**

Between 0.209 inches and 0.230 inches

#### Internal Configuration:

Field effect

# Electrode Internally-electrically Connected To Case:

Gate

**Mounting Method:** 

Terminal

Terminal Circle Diameter:

0.100 inches

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

-1.3 on-state drain to source voltage and 10.0 gate to source cutoff voltage

# **Current Rating Per Characteristic:**

-90.00 milliamperes zero-gate-voltage drain current

# **Power Rating Per Characteristic:**

500.0 milliwatts total power dissipation

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

3 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/476 government specification

#### Shelf Life:

N/a

#### Unit Of Measure:

--

### Demilitarization:

No

Fiig:

A110a0